



P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V(BR)DSS	Rds(on)	Ι _D T _A = +25°C
50)/	6Ω @ V _{GS} = -4 V	-200mA
-50V	8Ω @ V _{GS} = -2.5V	-160mA

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

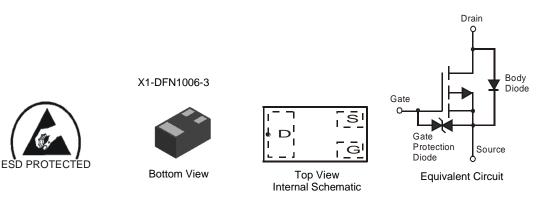
- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays

Features and Benefits

- Low On-Resistance
- ESD Protected Gate
- Low Input/Output Leakage
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: X1-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @
- Terminal Connections: See Diagram
- Weight: 0.001 grams (Approximate)



Ordering Information (Note 4)

Part Number	Case	Packaging
DMP56D0UFB-7	X1-DFN1006-3	3,000/Tape & Reel
DMP56D0UFB-7B	X1-DFN1006-3	10,000/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html



Marking Information

DMP56D0UFB-7	From date code 1527 (YYWW), this changes to: Top View Dot Denotes Drain Side Top View Bar Denotes Gate and Source Side	
DMP56D0UFB-7B	Top View Bar Denotes Gate and Source Side $D3 = Part Marking Code$ $(+ + + + + + + + + + + + + + + + + + +$	

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	-50	V
Gate-Source Voltage			V _{GSS}	±8	V
Drain Current (Note 5)	Steady	$T_A = +25^{\circ}C$	I _D	-200	mA
Pulsed Drain Current (Note 6)			I _{DM}	-700	mA

Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	425	mW
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R _{0JA}	275	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

5. Device mounted on FR-4 PCB. t \leq 5 sec. 6. Pulse width \leq 10µS, Duty Cycle \leq 1%. Notes:



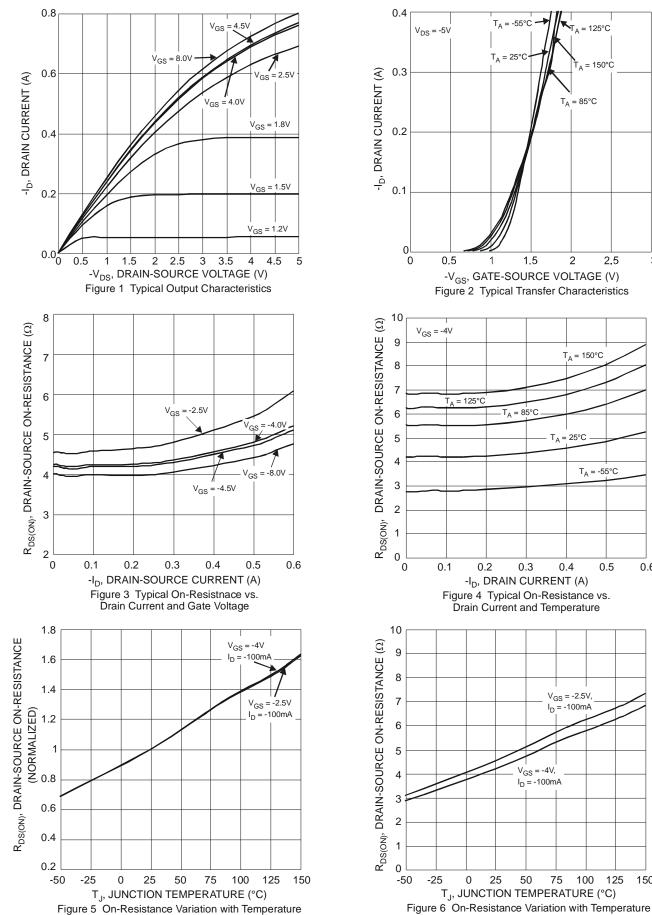
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

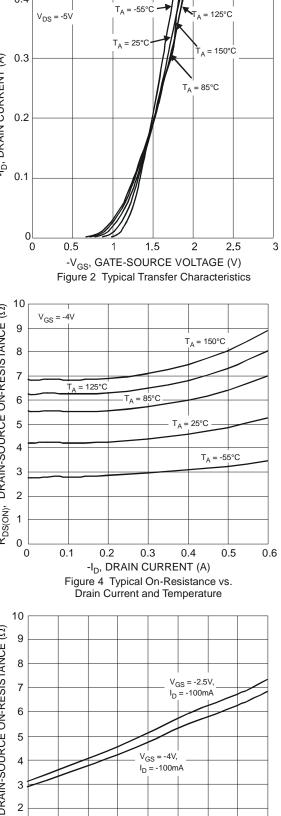
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)			•			
Drain-Source Breakdown Voltage	BV _{DSS}	-50	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_	—	-10	μA	$V_{DS} = -50V, V_{GS} = 0V$
Gate-Source Leakage	Igss	—	—	±1	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(th)}	-0.5		-1.2	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	P		4.6	6	Ω	$V_{GS} = -4.0V, I_D = -100mA$
	R _{DS (ON)}		6	8	12	$V_{GS} = -2.5V, I_D = -80mA$
Forward Transfer Admittance	Y _{fs}	100		—	mS	$V_{DS} = -5V, I_D = -100mA$
Diode Forward Voltage (Note 7)	V _{SD}	_	—	-1.2	V	$V_{GS} = 0V, I_{S} = -100mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	50.54	—	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	_	3.49	—	pF	
Reverse Transfer Capacitance	Crss	_	2.42	—	pF	
Gate Resistance	R _G	—	201	-	Ω	$V_{DS} = 0V, V_{GS} = 0V,$ f = 1.0MHz
Total Gate Charge V _{GS} = 4.5V	Qg	—	0.58	—	nC	$V_{GS} = -4V, V_{DS} = -25V,$ $I_D = -100mA$
Gate-Source Charge	Q _{gs}	—	0.09	—	nC	
Gate-Drain Charge	Q _{gd}	_	0.14	—	nC	
Turn-On Delay Time	t _{D(on)}		4.46	_	nS	
Turn-On Rise Time	tr		6.63	_	nS	$V_{DD} = -30V, I_D = -0.27A,$ $V_{GEN} = -4V, R_{GEN} = 6\Omega$
Turn-Off Delay Time	t _{D(off)}		21.9	—	nS	
Turn-Off Fall Time	t _f		15.0	_	nS	

 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing. Notes:

DMP56D0UFB







25

50

0

75

100

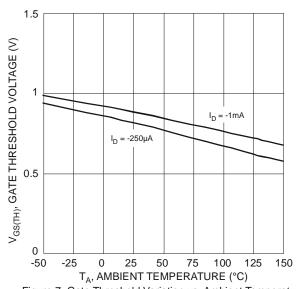
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DMP56D0UFB Document number: DS36175 Rev. 3 - 2

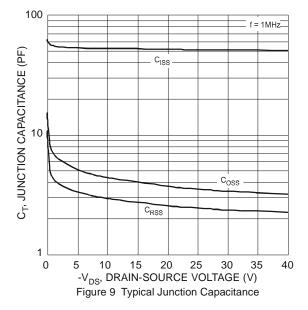
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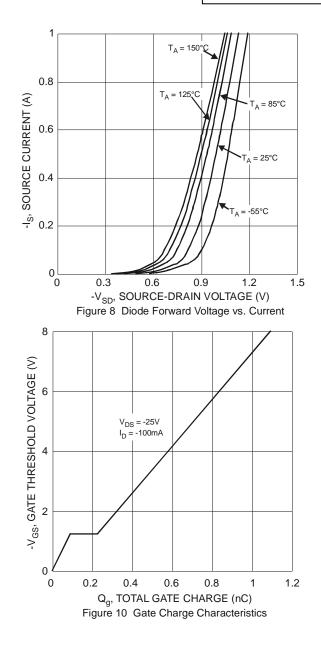
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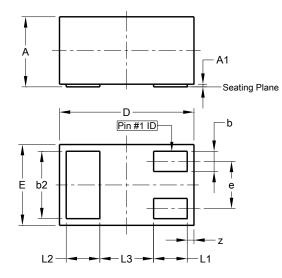






Package Outline Dimensions

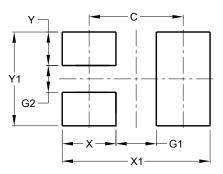
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X1-DFN1006-3						
Dim	Min	Max	Тур			
Α	0.47	0.53	0.50			
A1	0.00	0.05	0.03			
b	0.10	0.20	0.15			
b2	0.45	0.55	0.50			
D	0.95	1.075	1.00			
E	0.55	0.675	0.60			
е	-	-	0.35			
L1	0.20	0.30	0.25			
L2	0.20	0.30	0.25			
L3	-	-	0.40			
z	0.02	0.08	0.05			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.70
G1	0.30
G2	0.20
Х	0.40
X1	1.10
Y	0.25
Y1	0.70



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